

# KBP200-KBP210 SILICON BRIDGE RECTIFIERS

VOLTAGE RANGE: 50 - 1000V CURRENT: 2.0 A

### **Features**

- Diffused Junction
- Low Forward Voltage Drop
- High Current Capability
- High Reliability
- High Surge Current Capability
- Ideal for Printed Circuit Boards

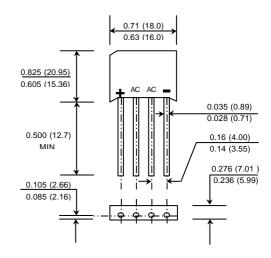
#### **Mechanical Data**

- Case: Molded Plastic
- Terminals: Plated Leads Solderable per
- MIL-STD-202, Method 208
   Polarity: As Marked on Body
- Woight: 1.7 grams (approx)
- Weight: 1.7 grams (approx.)Mounting Position: Any
- Marking: Type Number





## **KBP**



Dimensions in inches and (millimeter)

## Maximum Ratings and Electrical Characteristics T<sub>A</sub> = 25°C unless otherwise specified

Single phase, half wave, 60Hz, resistive or inductive load. For capacitive load, derate current by 20%.

Characteristic	Symbol	KBP 200	KBP 201	KBP 202	KBP 204	KBP 206	KBP 208	KBP 210	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	VRRM VRWM VR	50	100	200	400	600	800	1000	V
RMS Reverse Voltage	VR(RMS)	35	70	140	280	420	560	700	٧
Average Rectified Output Current (Note 1) @T <sub>A</sub> = 50°	c lo	2.0							Α
Non-Repetitive Peak Forward Surge Current 8.3ms Single half sine-wave superimposed on rated load (JEDEC Method)	IFSM	60				А			
Forward Voltage (per element) $@I_F = 2.0$	A VFM	1.1						V	
Peak Reverse Current $@T_A = 25$ At Rated DC Blocking Voltage $@T_A = 100$		10 500						μΑ	
Rating for Fusing (t<8.3ms)	l <sup>2</sup> t	15					A <sup>2</sup> s		
Typical Junction Capacitance per element (Note 2)	Cj				25				pF
Typical Thermal Resistance (Note 3)		30							K/W
Operating and Storage Temperature Range	Тj, Tsтg	-55 to +165				°C			

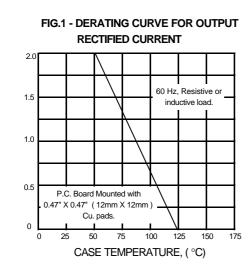
Note: 1. Leads maintained at ambient temperature at a distance of 9.5mm from the case.

- 2. Measured at 1.0 MHz and applied reverse voltage of 4.0V D.C.
- 3. Thermal resistance junction to ambient mounted on PC board with 12mm<sup>2</sup> copper pad.



# RATING AND CHARACTERISTIC CURVES (KBP200 - KBP210)

AVERAGE FORWARD OUTPUT CURRENT, AMPERES



PEAK FORWARD SURGE CURRENT, AMPERES

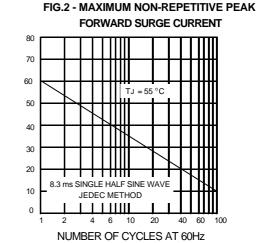


FIG.3 - TYPICAL FORWARD CHARACTERISTICS

PER DIODE

100

Pulse Width = 300 µs 1 % Duty Cycle =
1

#### FIG.4 - TYPICAL REVERSE CHARACTERISTICS

